

**Vishay Semiconductors** 



# **Small Signal Switching Diode, Dual**

#### Features

- Silicon Epitaxial Planar Diode
- Fast switching dual diode with common anode
- This diode is also available in other configurations including: a single with type designation BAL99, a dual anode to cathode with type designation BAV99, and a dual common cathode with type designation BAV70.
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### **Mechanical Data**

Case: SOT-23

Weight: approx. 8.8 mg

#### Packaging Codes/Options:

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box

GS08 / 3 k per 7" reel (8 mm tape), 15 k/box

#### Parts Table

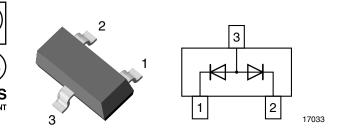
Part	Ordering code	Marking	Remarks
BAW56-V	BAW56-V-GS18 or BAW56-V-GS08	JD	Tape and Reel

#### **Absolute Maximum Ratings**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Repetitive peak reverse voltage = Working peak reverse voltage = DC Blocking voltage		V <sub>R</sub> = V <sub>RRM</sub>	70	V	
Forward continuous current		١ <sub>F</sub>	250	mA	
Non repetitive peak forward current	t <sub>p</sub> = 1 μs	I <sub>FSM</sub>	2	А	
	t <sub>p</sub> = 1 ms	I <sub>FSM</sub>	1	А	
	t <sub>p</sub> = 1 s	I <sub>FSM</sub>	0.5	A	
Power dissipation		P <sub>tot</sub>	350 <sup>1)</sup>	mW	

<sup>1)</sup> Device on fiberglass substrate, see layout



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#### **Thermal Characteristics**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambiant air		R <sub>thJA</sub>	430	K/W
Junction temperature		Тj	150	°C
Storage temperature range		T <sub>stg</sub>	- 65 to + 150	°C

<sup>1)</sup> Device on fiberglass substrate, see layout

#### **Electrical Characteristics**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	I <sub>F</sub> = 1 mA	V <sub>F</sub>			715	mV
	I <sub>F</sub> = 10 mA	V <sub>F</sub>			855	mV
	I <sub>F</sub> = 50 mA	V <sub>F</sub>			1000	mV
	I <sub>F</sub> = 150 mA	V <sub>F</sub>			1250	mV
Reverse current	V <sub>R</sub> = 70 V	I <sub>R</sub>			2.5	μA
	V <sub>R</sub> = 70 V, T <sub>j</sub> = 150 °C	I <sub>R</sub>			100	μA
	V <sub>R</sub> = 25 V, T <sub>j</sub> = 150 °C	I <sub>R</sub>			30	μA
Diode capacitance	V <sub>F</sub> = V <sub>R</sub> = 0, f = 1 MHz	CD			2	pF
Reverse recovery time	$I_F = 10 \text{ mA to } I_R = 1 \text{ mA},$ $V_R = 6 \text{ V}, \text{ R}_L = 100 \Omega$	t <sub>rr</sub>			6	ns

**Typical Characteristics** T<sub>amb</sub> = 25 °C, unless otherwise specified

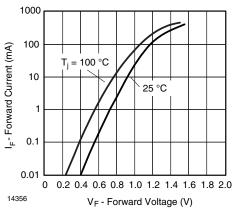


Figure 1. Forward Current vs. Forward Voltage

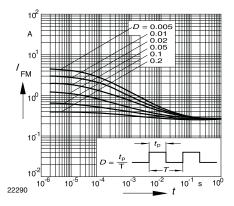


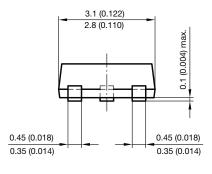
Figure 2. Peak forward current  $I_{FM} = f(t_p)$ 

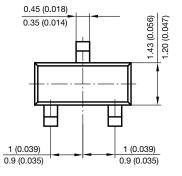


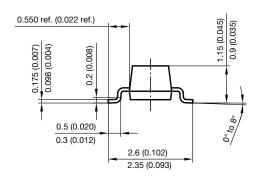
# BAW56-V

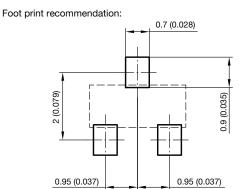
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### Package Dimensions in millimeters (inches): SOT-23









Document no.: 6.541-5014.01-4 Rev. 8 - Date: 23.Sept.2009



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